

TMR7502-C

Unibody Low Temperature-Drift Current Sensor

Description

TMR7502-C is an open loop current sensor for accurate measurement of DC, AC, pulsed current and arbitrary waveform current with galvanic isolation between primary and secondary circuits.



Features and Benefits

- Low temperature drift
- Galvanic isolation
- High immunity to external interference
- RoHS and REACH compliant

Applications

- DC motor drives
- Inverter and variable frequency drives (VFD)
- Uninterruptible power supplies (UPS)
- Power supplies for welding application
- Switching power supplies

Selection Guide

Model	Primary Nominal Current	Primary Current Measuring Range
TMR7502-5000C	500 A	±1500 A
TMR7502-6000C	600 A	±1800 A
TMR7502-8500C	850 A	±2550 A
TMR7502-1001C	1000 A	±3000 A
TMR7502-1201C	1200 A	±3600 A
TMR7502-1501C	1500 A	±4500 A
TMR7502-2001C	2000 A	±6000 A
TMR7502-2501C	2500 A	±6000 A
TMR7502-3001C	3000 A	±6000 A

Insulation and Environmental Characteristics

Parameters	Symbol	Typical	Unit
Dielectric Strength	V _D	5	kV(50Hz, 1min)
Insulation Resistance	R _{IS}	1000	MΩ
Creepage Distance	d _{CP}	23	mm
Clearance	d _{cL}	14	mm
Ambient Operating Temperature	T _A	-40 to +105	°C
Ambient Storage Temperature	T _{STG}	-50 to +105	°C
Mass for I _{PN} < 850 A	m	300	g
Mass for I _{PN} ≥ 850A	m	450	g





Catalogue

1. Specifications	03
2. Typical Output Characteristics	04
3. Typical Temperature Characteristics	05
4. Parameters Definition And Formula	08
5. Application Information	09
6. Dimensions	. 10



-



1. Specifications

 T_{A} = +25 °C, V_{CC} = ±15 V, R_{L} = 10 k $\Omega,$ unless otherwise noted

Parameter	Symbol		onditions	Min.	Тур.	Max.	Unit
		G	eneral Electrical Data		,		
		TMR7502-5000C		-	500	-	A
		TMR7502-6000C		-	600	-	
	I _{PN}	TMR7502-8500C		-	850	-	
Primary Nominal		TMR7502-1001C		-	1000	-	
Current		TMR7502-1201C		-	1200	-	
-		TMR7502-1501C		-	1500	-	
		TMR7502-2001C		-	2000	-	
		TMR7502-2501C		-	2500	-	
		TMR7502-3001C		-	3000	-	
		TMR7502-5000C		-1500	-	1500	
		TMR7502-6000C		-1800	-	1800	
		TMR7502-8500C		-2550	-	2550	
Primary Current			7502-1001C	-3000	-	3000	
Measuring Range	I _{PM}		7502-1201C	-3600	-	3600	A
			7502-1501C	-4500	-	4500	_
			7502-2001C	-6000	-	6000	-
		TMR7502-2501C		-6000	-	6000	
		TMR	7502-3001C	-6000	-	6000	
	S	$I_{P} = 0$ to $\pm I_{PN}$	TMR7502-5000C	-	8.00	-	mV/A
			TMR7502-6000C	-	6.67	-	
			TMR7502-8500C	-	4.71	-	
0			TMR7502-1001C	-	4.00	-	
Sensitivity			TMR7502-1201C	-	3.33	-	
			TMR7502-1501C	-	2.67	-	
			TMR7502-2001C	-	2.00	-	
			TMR7502-2501C	-	1.60	-	
Output Voltage	V	TMR7502-3001C		-	1.33 V _{OE} + S × I _P	-	V
Supply Voltage	V _{OUT} V _{CC}	$I_P = 0$ to $\pm I_{PM}$		-	±15	-	V
Current Consumption		±5 %		-	+25/-5	-	mA
Load Resistance	R _L	$I_{\rm P} = 0$ $I_{\rm P} = 0 \text{ to } \pm I_{\rm PN}$		1	10		kΩ
Load Capacitance		$I_P = 0$ to $\pm I_{PN}$		-	100	-	pF
Load Oapaolanoc	ΟL		atic Performance Data		100		Pi
		$T_A = +25 \text{ °C}, I_P = 0 \text{ to } \pm I_{PN}$		-1.2	±0.5	1.2	
Accuracy	X_{G}		$T_A = -40 \text{ °C to } +105 \text{ °C, } I_P = 0 \text{ to } \pm I_{PN}$		±1.5	3.5	- % I _{PN}
Linearity Error	٤L	$T_A = -40$ °C to +105 °C, $I_P = 0$ to $\pm I_{PN}$ $T_A = -40$ °C to +105 °C, $I_P = 0$ to $\pm I_{PN}$		-4.5	±0.5	-	% I _{PN}
Symmetry	ε _{sym}	$T_A = -40$ °C to +105 °C, $I_P = 0$ to $\pm I_{PN}$ $T_A = -40$ °C to +105 °C, $I_P = 0$ to $\pm I_{PN}$		99	100	101	%
Sensitivity Error	ε _s	$T_A = -40$ °C to +105 °C, $I_P = 0$ to $\pm I_{PN}$ $T_A = -40$ °C to +105 °C, $I_P = 0$ to $\pm I_{PN}$		-3	-	3	%
Offset Error	Т		+25 °C, $I_P = 0$	-25	±10	25	- mV
	V _{OE}		$T_A = -40$ °C to +105 °C, $I_P = 0$		±20	40	
Hysteresis	V _{OH}	$I_{P} = \pm I_{PN} \rightarrow 0$		-40 -10	±5	10	mV
,	Un	· · · · ·	amic Performance Data			-	<u> </u>
Response Time	t _R	di/dt > 50 A/ μ s, 10% to 90% of I _{PN}		-	5	-	μs
Bandwidth	BW		-3 dB	DC	25	-	kHz



.



2. Typical Output Characteristics

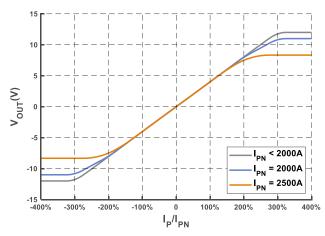


Figure 1. Output Voltage vs Primary Current

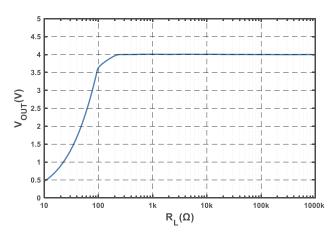
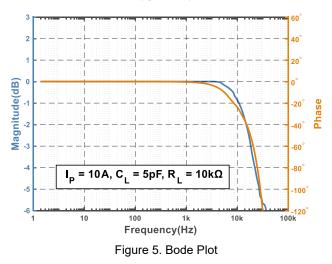


Figure 3. Output Voltage vs Load Resistance $(@I_P = I_{PN})$



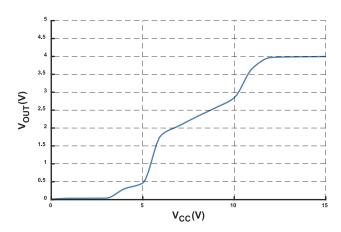


Figure 2. Output Voltage vs Supply Voltage (@ $I_P = I_{PN}$)

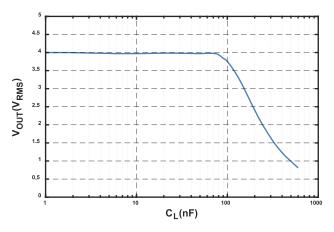


Figure 4. Output Voltage vs Load Capacitance $(\textcircled{O}I_{P} = I_{PN})$





AVG-

3. Typical Temperature Characteristics

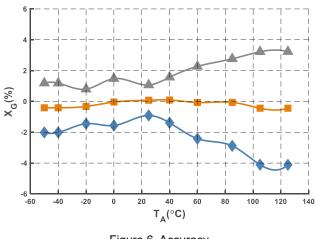


Figure 6. Accuracy

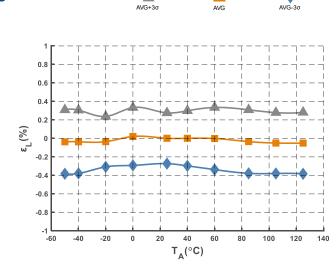


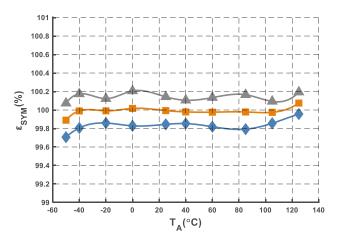
Figure 7. Linearity Error

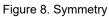
50

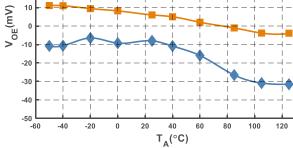
40

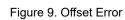
30

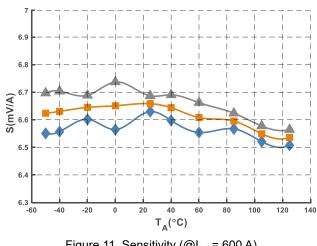
20











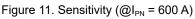


Figure 10. Sensitivity (@I_{PN} = 500 A)

40

T_A(°C)

60

80

100

120 140

20

8.3

8.2

8.1

(W//W)8 7.9

7.8

7.7

-60

-40

-20

0



140



Typical Temperature Characteristics

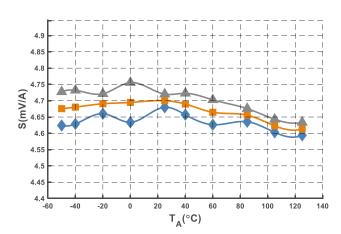
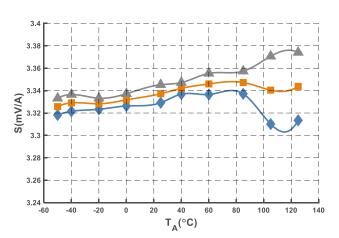
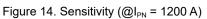


Figure 12. Sensitivity (@ I_{PN} = 850 A)





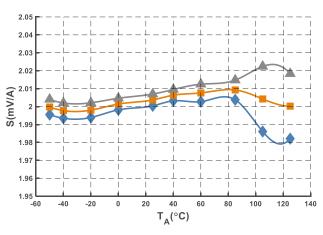


Figure 16. Sensitivity (@ I_{PN} = 2000 A)

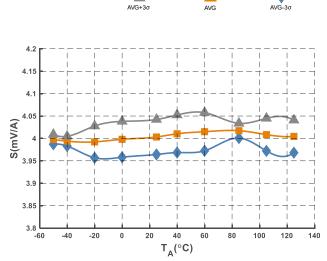
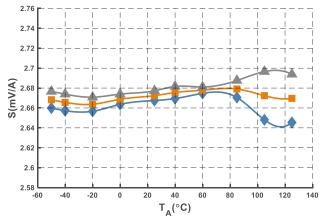
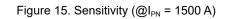


Figure 13. Sensitivity (@ I_{PN} = 1000 A)





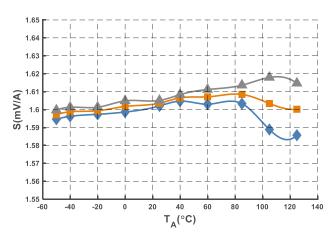
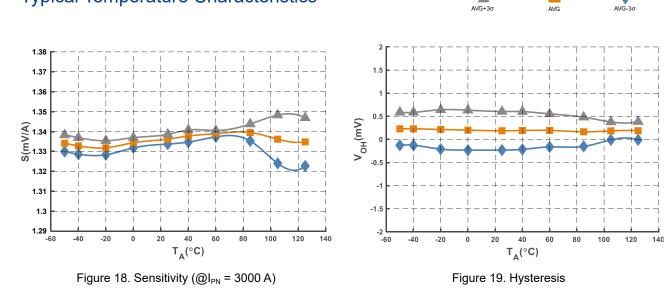


Figure 17. Sensitivity (@ I_{PN} = 2500 A)





Typical Temperature Characteristics







4. Parameters Definition And Formula

1) Output Voltage

$$V_{OUT} = V_{OE} + S \times I_P$$

 V_{OUT} stands for current sensor output voltage at given primary current, V_{OE} stands for offset error, S stands for sensitivity, I_P stands for primary current.

2) Accuracy

$$X_{G} = \max_{I_{P} \in [-I_{PN}, I_{PN}]} \left(\frac{V_{OUT} - (S \times I_{P})}{S \times I_{PN}} \times 100\% \right)$$

 $I_{\text{PN}}\,$ stands for nominal primary current

3) Sensitivity

$$S = \frac{V_{OUT_{(@ I_{PN})}} - V_{OUT_{(@ -I_{PN})}}}{2 \times I_{PN}}$$

 $V_{OUT_{\left(\textcircled{0}^{l}I_{PN} \right)}}$ and $V_{OUT_{\left(\textcircled{0}^{-l}PN \right)}}$ stand for the voltage output at I_{PN} and $-I_{PN}$ respectively.

4) Linearity

$$\epsilon_{L} = \underset{I_{P} \in [-I_{PN}, I_{PN}]}{MAX} \left(\frac{V_{OUT} - \left(\overline{V}_{OE} + \overline{S} \times I_{P}\right)}{S \times I_{PN}} \times 100\% \right)$$

 \overline{S} and \overline{V}_{OE} stand for the average values of the sensitivity and offset error.

5) Symmetry

$$\varepsilon_{\text{SYM}} = \left| \frac{V_{\text{OUT}(@ I_{\text{PN}})} - \overline{V}_{\text{OE}}}{V_{\text{OUT}(@ -I_{\text{PN}})} - \overline{V}_{\text{OE}}} \right| \times 100\%$$

6) Hysteresis

V_{OH} = MAX ΔH

△H is the maximum residual voltage between full scale positive and negative nominal current.





5. Application Information

Electrical Connection

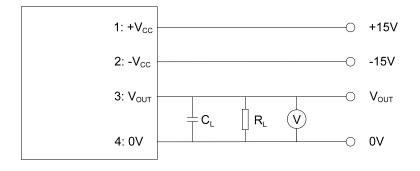


Figure 20. Electrical Connection

Mounting Recommendation

1. Mounting method:	$1 \times \Phi$ 5.5 mm hole and $1 \times \Phi$ 5.5 mm slotted hole		
	2 × M5 copper	or SS304 screws (Recommended torque 2.5 N·m)	
	Or		
	1 × Φ 5.5 mm l	hole and 2 × Φ 5.5 mm slotted holes	
	3 × M5 copper or SS304 screws (Recommended torque 2.5 N·m)		
2. Primary through hole dimensions:		64 mm × 21 mm	
3. Secondary electrical connection:		Molex 22111041 (old PN: Molex 5045-04A)	
		Crimp Housing: Molex 22011042	
		Crimping Terminal: Molex 08500102	

Remarks

- 1. V_{OUT} is positive when the primary current (I_P) is in the same direction as the arrow indication on the label and vice versa.
- 2. Improper connection may result in permanent damage of the sensor.
- 3. Excessive capacitive load may result in distortion of output signals when measuring high frequency primary signal. Please refer to Output Voltage vs Load Capacitance Curve.
- 4. Dynamic performances (di/dt and response time) are best with a single busbar completely filling the primary through hole.
- 5. Sensor is customizable upon request.





6. Dimensions

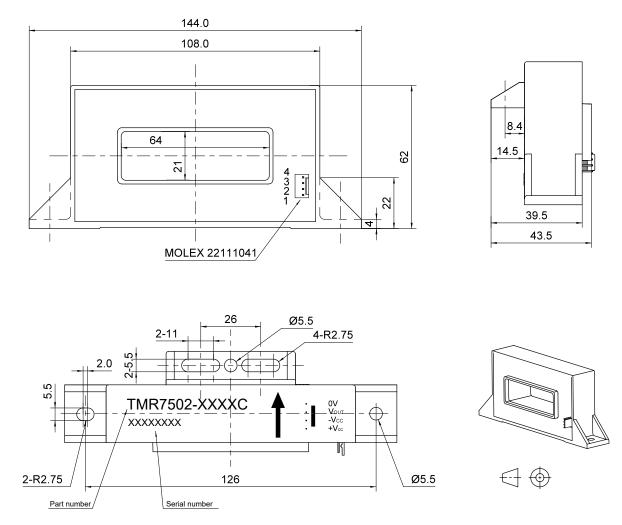


Figure 21. Dimension (unit: mm, tolerances for unmarked scales ±1 mm)



Copyright © 2022 by MultiDimension Technology Co., Ltd.

Information furnished herein by MultiDimension Technology Co., Ltd. (hereinafter MDT) is believed to be accurate and reliable. However, MDT disclaims any and all warranties and liabilities of any kind, with respect to any examples, hints or any performance or use of technical data as described herein and/or any information regarding the application of the product, including without limitation warranties of non-infringement of intellectual property rights of any third party. This document neither conveys nor implies any license under patent or other industrial or intellectual property rights. Customer or any third-party must further determine the suitability of the MDT products for its applications to avoid the applications default of customer or third-party. MDT accept no liability in this respect.

MDT does not assume any liabilities of any indirect, incidental, punitive, special or consequential damages (including without limitation of lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory. Notwithstanding any damages that customer might incur for any reason whatsoever, MDT's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the terms and conditions of commercial sale of MDT.

Absolute maximum ratings are the extreme limits the device will withstand without damage to the MDT product. However, the electrical and mechanical characteristics are not guaranteed as the maximum limits (above recommended operating conditions) are approached. MDT disclaims any and all warranties and liabilities of the MDT product will operate at absolute maximum ratings.

Specifications may change without notice.

Please download latest document from our official website www.dowaytech.com/en.

Recycling

The product(s) in this document need to be handed over to a qualified solid waste management services company for recycling in accordance with relevant regulations on waste classification after the end of the product(s) life.



No.2 Guangdong Road, Zhangjiagang Free Trade Zone, Jiangsu, China Web: www.dowaytech.com/en E-mail: info@dowaytech.com

